

## 具有防破音功能的免电感滤波2×20W D类立体声音频功放

### 2×20W Inductor Free Class D Stereo Amplifier with Anti-Clipping Function

#### ■ FEATURES

- Output Power (BTL)  
2×22W (VDD=14V, RL=4Ω, THD+N=10%)
- Output Power (PBTL)  
34W (VDD=16V, RL=4Ω, THD+N=10%)
- Single Wide Voltage Supply: 4.5V-17V
- Anti-clipping Function (ACF)
- Efficiency > 90%
- Differential / Single-ended Analog Input, BTL or PBTL Output
- Gain: 32dB
- Integrated Self-protection Circuits Including Overvoltage, Undervoltage, Overtemperature, DC-detect, and Overcurrent with Error Reporting
- LF and HF Package of ESOP16
- 输出功率 (BTL模式)  
2×22W (VDD=14V, RL=4Ω, THD+N=10%)
- 输出功率 (PBTL模式)  
34W (VDD=16V, RL=4Ω, THD+N=10%)
- 单电源系统, 4.5V-17V宽电压输入范围
- ACF防破音功能可选
- 超过90%效率, 无需散热器
- 扩频功能, 免电感滤波
- 模拟差分/单端输入, 输出模式立体声/单声道可选
- 增益: 32dB
- 保护功能: 过压/过流/过热/欠压异常, 直流检测和短路保护
- 无铅无卤封装, ESOP16

#### ■ APPLICATIONS

- Sound Bars
- Wireless Speakers
- Consumer Audio Applications
- TVs/Monitors
- 条形音箱
- 便携式音箱
- 拉杆音箱
- 无线智能音箱
- 消费类音频应用
- LCD电视/监视器

#### ■ DESCRIPTION

HT316C is a stereo efficient, Class-D audio amplifier for driving speakers up to 34W/4 Ω in mono PBTL. It can also deliver 2×20W/4Ω power in stereo BTL.

Advanced EMI Suppression enables the use of inexpensive ferrite bead filters while meeting EMC requirements for system cost reduction.

HT316C is fully protected against faults with Overvoltage, Undervoltage, Overtemperature, DC-detect, and Overcurrent protection. Faults can be reported to the processor to prevent devices from being damaged.

HT316C features Anti-Clipping Function (ACF) which detects output signal clip due to the over input signal and suppresses the output signal clip automatically. Also, the ACF function can adapt the output clip caused by power supply voltage down with battery. It can significantly improve the sound quality, creating a very comfortable musical enjoyment, and to protect the speakers from overload damage.

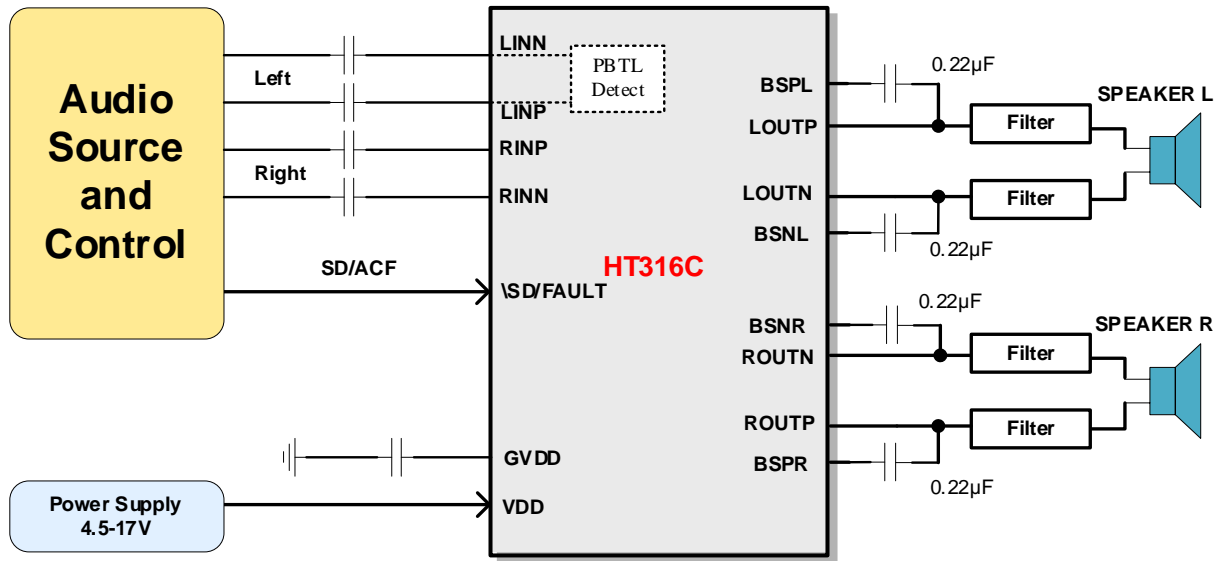
HT316C是一款高效D类音频功率放大器。在14V供电的立体声(BTL)模式、THD+N=10%条件下,能够持续提供2\*20W/4 Ω功率输出;在单声道(PBTL)、模式、THD+N=10%条件下,能够持续提供34W/4 Ω功率输出。

HT316C具有先进的扩频功能来抑制EMI,使用价格低廉且小体积铁氧体磁珠可满足EMC要求。

此外,HT316C内置关断功能使待机电流最小化,还集成了过压保护、直流保护、短路保护、热保护和电源欠压异常保护等功能,可全面防止出现故障。

HT316C具有防削顶失真(ACF)输出控制功能,可检测并抑制由于输入音乐、语音信号幅度过大所引起的输出信号削顶失真(破音),也能自适应地防止在BOOST升压电压下降所造成的输出削顶,显著提高音质,创造非常舒适的听音享受,并保护扬声器免受过载损坏。

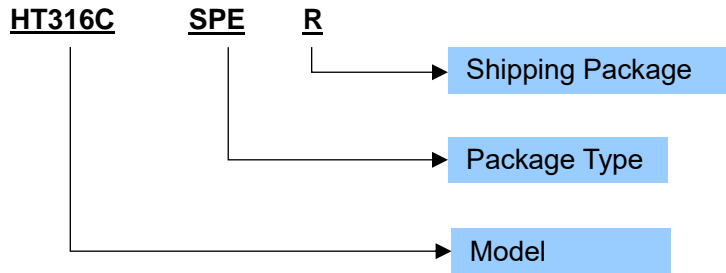
■ TYPICAL APPLICATION



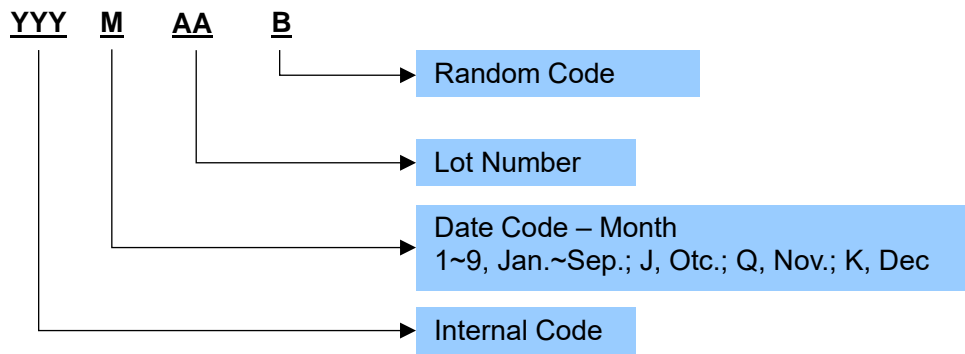
**ORDERING INFORMATION**

Part Number	Package Type	Marking	Operating Temperature Range	Shipping Package / MOQ
HT316CSPER	ESOP16 (SPE)	HT316C YYYMAAB <sup>1</sup>	-40℃~85℃	Tape and Reel (R) / 2500pcs

**Part Number**

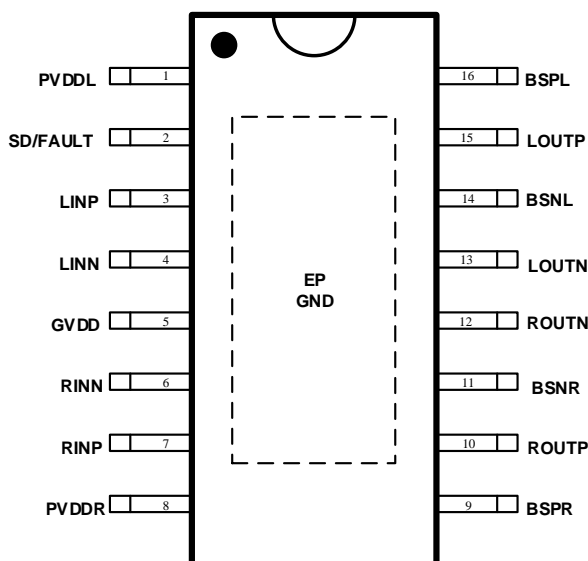


**Production Tracking Code**



<sup>1</sup> YYYMAAB is production tracking code

### ■ TERMINAL CONFIGURATION



**HT316C Top View**

### ■ TERMINAL FUNCTION

Terminal No.	Name	I/O <sup>1</sup>	Description
1	PVDDL	P	Power Supply for internal power circuitry of Channel L. 左声道功率电源
2	\SD/FAULT	I	SD/FAULT, multi-function pin. When pulled down, place the speaker amplifier in shutdown mode. General fault reporting including Over-Temp, Over-Current, DC Detect. 接地时功放关闭。发生过温、过流、DC等保护时，该引脚拉低
3	LINP	I	Positive input terminal for L channel. 左声道输入正端
4	LINN	I	Negative input terminal for L channel. 左声道输入负端
5	GVDD	O	Voltage regulator derived from PVDD supply. 内部整流输出，接1uF电容到地
6	RINN	I	Negative input terminal for R channel. 右声道输入负端
7	RINP	I	Positive input terminal for R channel. 右声道输入正端
8	PVDDR	P	Power Supply for internal power circuitry of Channel R. 右声道功率电源
9	BSPR	BST	Connection point for the ROUPT bootstrap capacitor, which is used to create a power supply for the high-side gate drive for ROUPT. ROUPT自举电容位
10	ROUPT	O	Positive pin for differential speaker amplifier output R. 右声道输出正端
11	BSNR	BST	Connection point for the ROUTN bootstrap capacitor, which is used to create a power supply for the high-side gate drive for ROUTN. ROUTN自举电容位
12	ROUTN	O	Negative pin for differential speaker amplifier output R. 右声道输出负端
13	LOUTN	O	Negative pin for differential speaker amplifier output L. 左声道输出负端
14	BSNL	BST	Connection point for the LOUPTN bootstrap capacitor, which is used to create a power supply for the high-side gate drive for LOUPTN. LOUPTN自举电容位
15	LOUPT	O	Positive pin for differential speaker amplifier output L. 左声道输出正端
16	BSPL	BST	Connection point for the LOUPT bootstrap capacitor, which is used to create a power supply for the high-side gate drive for LOUPT. LOUPT自举电容位
EP	GND	G	Provides both <b>electrical and thermal connection</b> from the device to the Board, make sure it is connected to the system ground. 既是地，又是散热PAD

<sup>1</sup> I: Input; O: Output; G: Ground; P: Power; BST: BOOT Strap; OD: Open drain

**■ SPECIFICATIONS<sup>1</sup>**
**● Absolute Maximum Ratings<sup>2</sup>**

PARAMETER	Symbol	MIN	MAX	UNIT
Supply voltage range (PVDD, AVCC)	PVDD	-0.3	18	V
Input voltage range (LINP, LINN, RINP, RINN, \SD, MODE, GAIN)	V <sub>I</sub>	-0.3	5.8	V
Operating temperature range	T <sub>A</sub>	-40	85	°C
Operating junction temperature range	T <sub>J</sub>	-40	150	°C
Storage temperature range	T <sub>STG</sub>	-50	150	°C

**● Recommended Operating Conditions**

PARAMETER	Symbol	CONDITION	MIN	TYP	MAX	UNIT
Supply voltage range	V <sub>DD</sub>	PVDD, AVCC	4.5		17	V
Operating temperature	T <sub>a</sub>		-40	25	85	°C
High-level input voltage	V <sub>IH</sub>	\SD terminal, ACF off	2.5		5.5	V
Middle-level input voltage	V <sub>IM</sub>	\SD terminal, ACF on	1.8		2.1	V
Low-level input voltage	V <sub>IL</sub>	\SD terminal, shutdown			0.5	V
Low-level output voltage	V <sub>OL</sub>	\SD/Fault terminal, when fault occurs, OPEN-DRAIN OUTOUT			0.5	V
Load impedance (BTL)	R <sub>L</sub>	With output filter	3.2	4		Ω
Load impedance (PBTL)	R <sub>L</sub>	With output filter	1.6	2		Ω

**● Electrical Specification<sup>3</sup>**

- Conditions: T<sub>A</sub> = 25°C, PV<sub>DD</sub> = 4.5-17V, Load = 4ohm, unless otherwise specified.

PARAMETER	Symbol	CONDITION	MIN	TYP	MAX	UNIT
Class Output Offset Voltage	V <sub>OS</sub>	V <sub>I</sub> = 0V, Gain = 32dB		1.5		mV
Quiescent supply current	I <sub>DD</sub>	V <sub>DD</sub> = 12V, No Load		10		mA
Quiescent supply current in SD mode	I <sub>SD</sub>	V <sub>DD</sub> = 12V, With Load		14		uA
System Gain in BTL or PBTL mode	Gain			32		dB
Turn-on time	t <sub>on</sub>	Pull \SD high or power on		80		ms
Turn-off time	t <sub>off</sub>	Pull \SD low		5		us
Gate drive supply	GVDD			5		V

<sup>1</sup> Depending on parts and PCB layout, characteristics may be changed.

<sup>2</sup> Stresses beyond those listed under absolute maximum ratings may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under recommended operating conditions is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

<sup>3</sup> Depending on parts and pattern layout, characteristics may be changed.

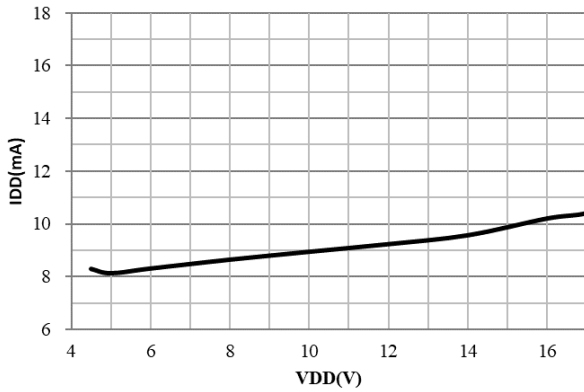
Conditions:  $T_A = 25^\circ\text{C}$ ,  $P_{VDD} = 4.5\text{-}17\text{V}$ , Load = Filter +  $R_L$ , Filter = 300R Bead + 1nF,  $R_L = 4\Omega + 22\mu\text{H}$ ,  $f_{IN} = 1\text{ kHz}$ , Gain = 26dB,  $C_{IN} = 1\mu\text{F}$ , 20-20kHz, unless otherwise specified.

PARAMETER	Symbol	CONDITION	MIN	TYP	MAX	UNIT
Continuous output power	$P_o$	BTL, $V_{DD} = 12\text{V}$ , $R_L = 4\Omega$	THD +N = 1%		14	W
			THD+N = 10%		17	W
		BTL, $V_{DD} = 12\text{V}$ , $R_L = 8\Omega$	THD +N = 1%		8	W
			THD+N = 10%		10	W
		PBTL, $V_{DD}=16\text{V}$ , $R_L = 4\Omega$ ,	THD +N = 1%		28	W
			THD+N = 10%		34	W
Total harmonic distortion + noise	THD+N	$P_o = 1\text{W}$ , $V_{DD} = 12\text{V}$ , $R_L = 4\Omega$		0.05		%
Efficiency	$\eta$	$V_{DD} = 12\text{V}$ , THD+N = 10%	$R_L = 4\Omega$ , BTL		86	%
			$R_L = 8\Omega$ , BTL		92	%
Cross Talk	CT	$P_o = 1\text{W}$ , Gain = 17.6dB, 1kHz		-90		dB
Output integrated noise	$V_N$	A-weighted, Gain = 17.6 dB		80		$\mu\text{V}$
Signal-to-noise ratio	SNR	A-weighted, Gain = 17.6 dB, $P_o = 1\text{W}$		87		dB
Power supply rejection ratio	PSRR	200mVpp 1kHz, Input grounded		-75		dB
Oscillator frequency	$f_{osc}$			360		kHz
Over temperature protection trigger point	OTP			150		$^\circ\text{C}$
Over current trip point	OCP			7.5		A

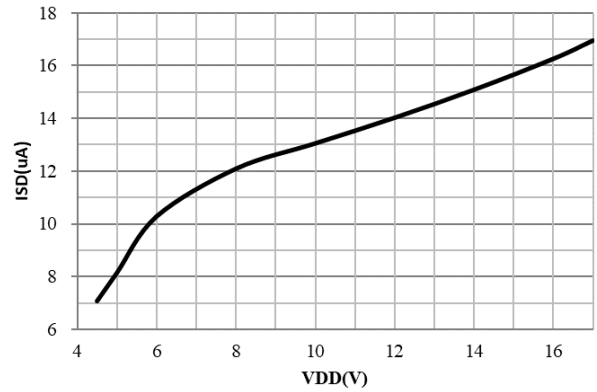
**TYPICAL OPERATING CHARACTERISTICS**

VDD = 12V, Load = 4ohm, unless otherwise specified.

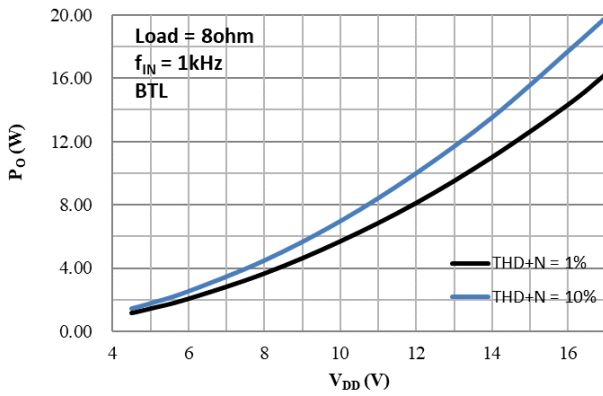
**I<sub>DD</sub> vs V<sub>DD</sub>**



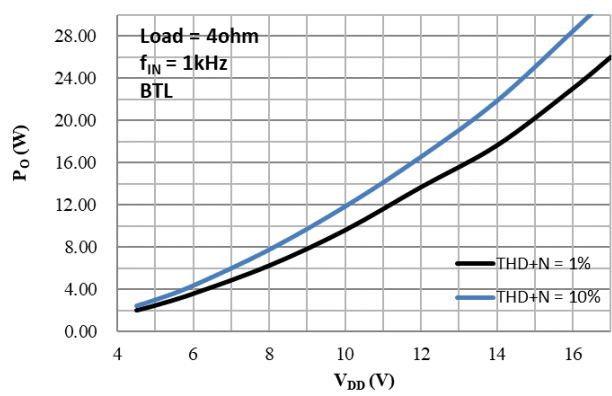
**I<sub>SD</sub> vs V<sub>DD</sub>**



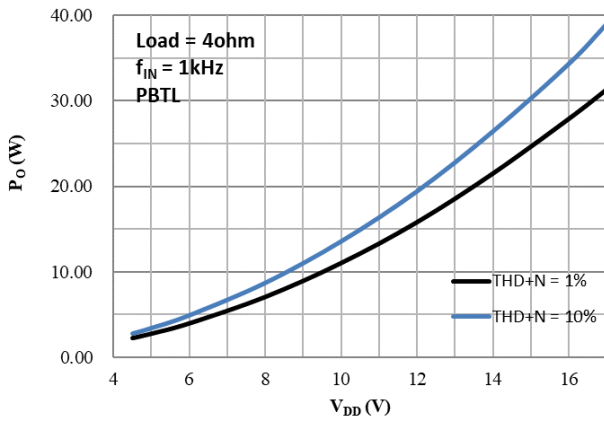
**V<sub>DD</sub> vs P<sub>O</sub>**



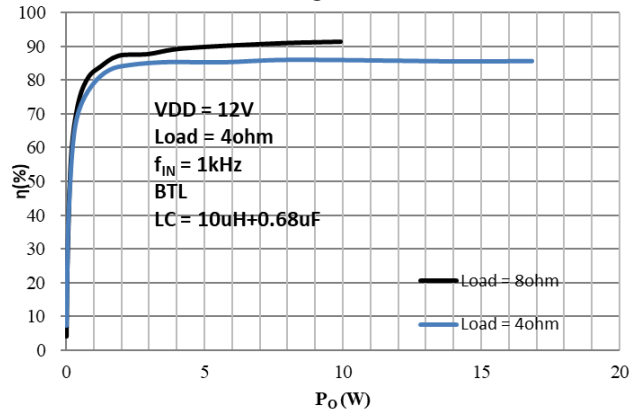
**V<sub>DD</sub> vs P<sub>O</sub>**



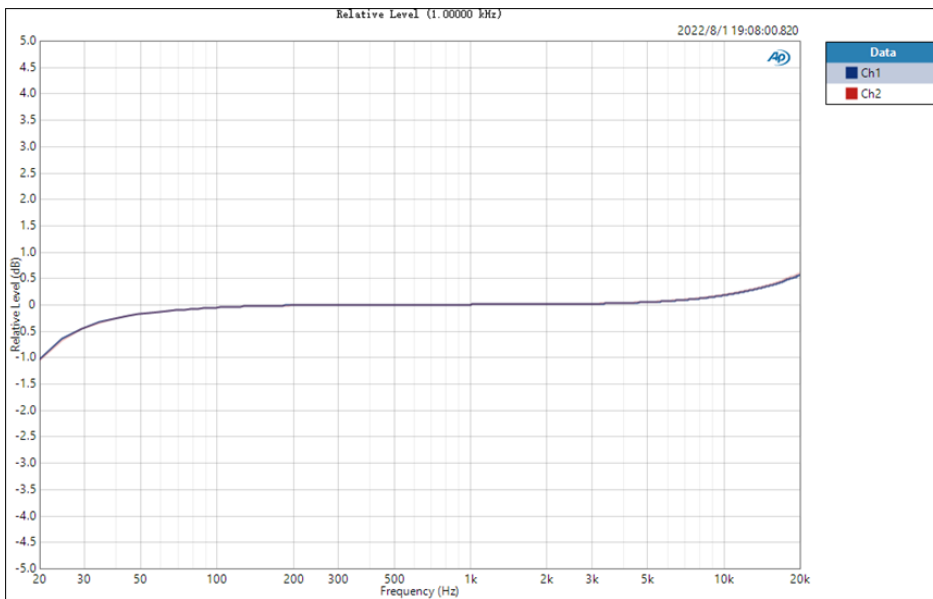
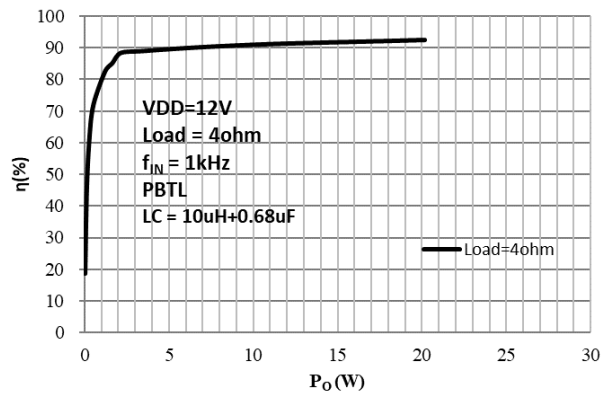
**V<sub>DD</sub> vs P<sub>O</sub>**



**P<sub>O</sub> vs η**



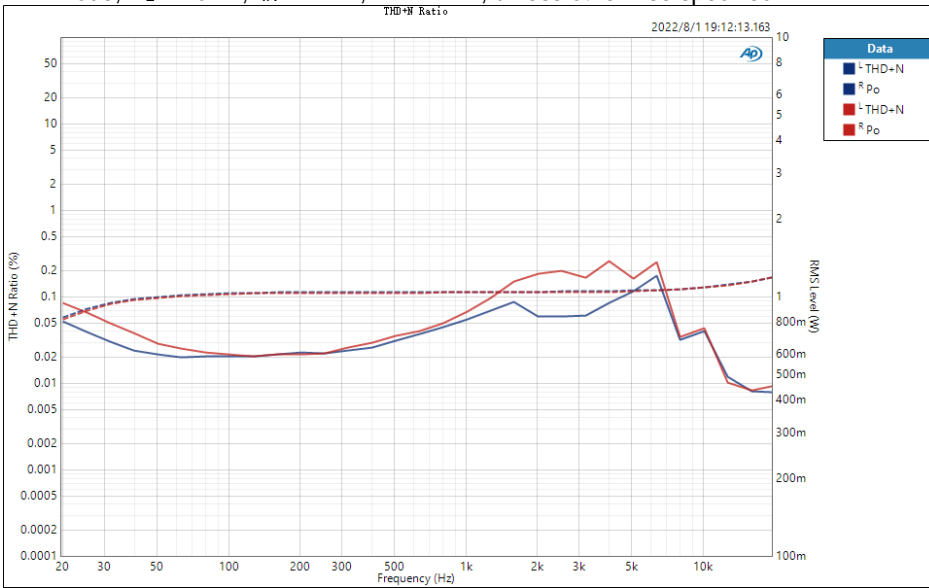
**$P_O$  vs  $\eta$**



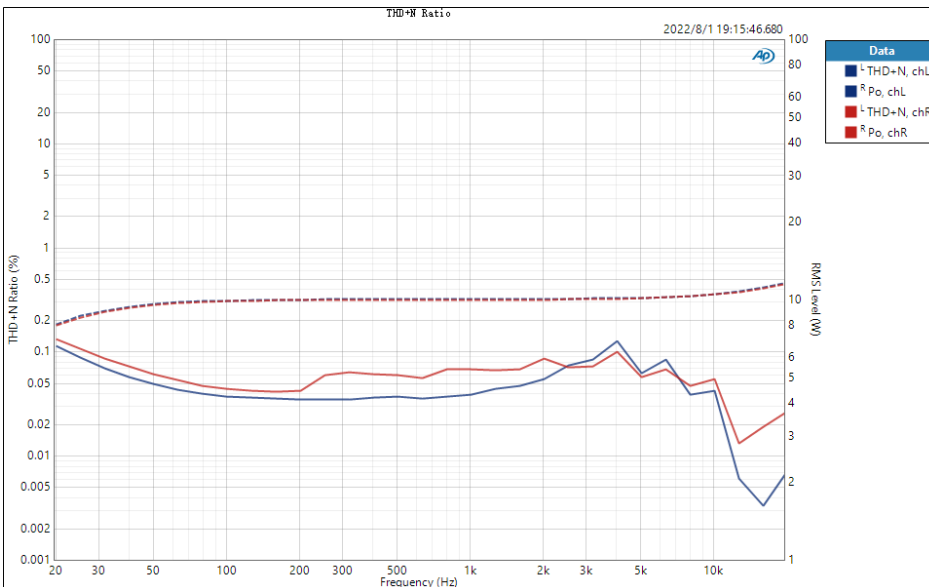
Frequency respond  
( $C_{in} = 1\mu\text{F}$ ,  $R_{in}=10\text{k}$ )



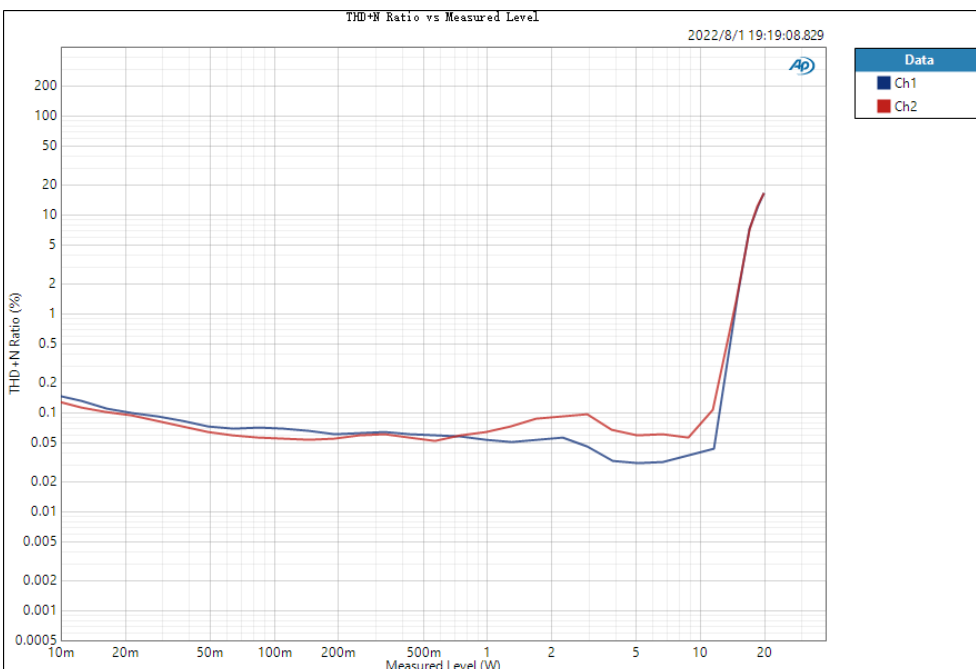
BTL mode,  $R_L = 4\Omega$ ,  $f_{IN} = 1\text{kHz}$ ,  $V_{DD} = 12\text{V}$ , unless otherwise specified.



frequency vs THD+N  
( $P_o \approx 2 \times 1\text{W}$ )



frequency vs THD+N  
( $P_o \approx 2 \times 10\text{W}$ )



Output power vs THD+N

## APPLICATION INFORMATION

### 1 Power Supply

The power supply for the HT316C only requires one voltage from 4.5V to 17V, which supplies the analog circuitry and the power stage.

GVDD is the LDO output derived from PVDD, and it should connect a filtering capacitor 1uF.

Filtering capacitors of 100nF//1uF//220uF for each PVDD should be placed close to the PVDD pin.

### 2 Amplifier Input and Output

#### 2.1 Amplifier Input Configuration

HT316C is an amplifier with analog input (single-ended or differential).

For a differential operation, input signals into INP and INN pins via DC-cut capacitors ( $C_{IN}$ ) and external input resistors  $R_{EIN}$ . See as figure 1. The system gain can be calculated by  $Gain \approx 20 \times \log\left(\frac{R_F}{R_{IIN} + R_{EIN}}\right)$ , where  $R_F = 400k$ ,  $R_{IIN} = 10k$ . And the high pass cut-off frequency of input signal can be calculated by  $f_c = \frac{1}{2\pi(R_{IIN} + R_{EIN}) \times C_{IN}}$ .

For a single-ended operation, input signals to INP pin via a DC-cut capacitor ( $C_{IN}$ ) and external input resistor ( $R_{EIN}$ ). INN pin should be connected to ground via a DC-cut capacitor and external input resistor (with the same value of  $C_{IN}$  and  $R_{EIN}$ ). See as figure 2. The Gain and high pass Cut-off frequency are the same as the above case.

HT316C 仅需要一种电源供电，即在 PVDDL 和 PVDDR 端加 4.5~17V。PVDD 端建议各加 100nF//1uF//220uF 的并联电容到地。

GVDD 是 LDO 输出，接 1uF 电容到地进行滤波。

HT316C 接受模拟差分或单端音频信号输入，产生 PWM 脉冲输出信号驱动扬声器。

对差分输入，通过隔直电容  $C_{IN}$  和输入电阻  $R_{EIN}$  分别输入到 INP 和 INN 端，见图 1。系统增益  $Gain \approx 20 \times \log\left(\frac{R_F}{R_{IIN} + R_{EIN}}\right)$ ，其中  $R_F = 400k$ ， $R_{IIN} = 10k$ 。高通滤波器截止频率为  $f_c = \frac{1}{2\pi(R_{IIN} + R_{EIN}) \times C_{IN}}$ 。

对单端输入，则通过  $C_{IN}$  耦合到 INP 端。INN 端必须通过输入电阻和电容（与  $C_{IN}$ 、 $R_{EIN}$  值相同）接地，见图 2。增益 Gain 和截止频率  $f_c$  与差分输入时相同。。

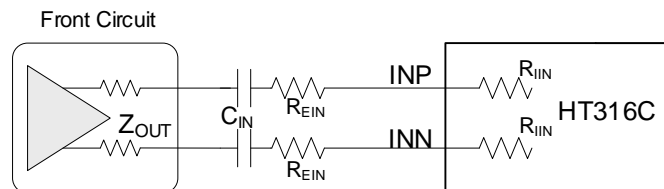


Figure 1 Differential Input configuration

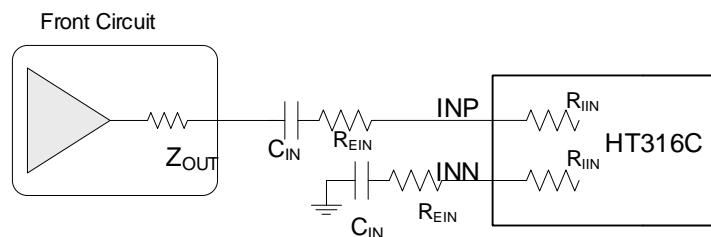


Figure 2 Single-ended Input configuration

## 2.2 Amplifier Output Configuration

The HT316C has been tested with a simple ferrite bead filter for a variety of applications including long speaker wires up to 10 cm and high power. One important aspect of the ferrite bead selection is the type of material used in the ferrite bead. Not all ferrite material is alike, so it is important to select a material that is effective in the 10 to 100 MHz range which is key to the operation of the class-D amplifier. The impedance of the ferrite bead can be used along with a small capacitor with a value in the range of 1000 pF to reduce the frequency spectrum of the signal to an acceptable level. For best performance, the resonant frequency of the ferrite bead/capacitor filter should be less than 10 MHz. Also, the filter capacitor can be increased if necessary, with some impact on efficiency.

HT316C 可使用简单的铁氧体珠过滤器，在各种应用中，包括高达 10 厘米的扬声器线和较大的功率。铁氧体珠选择的一个重要方面是铁氧体珠所用材料的类型。并不是所有的铁氧体材料都是一样的，所以选择一种在 10 到 100 MHz 范围内有效的材料是很重要的，这是 D 类放大器工作的关键。铁氧体珠的阻抗可与值在 1000 pF 范围内的小电容一起使用，以将信号的频谱降低到可接受的范围。

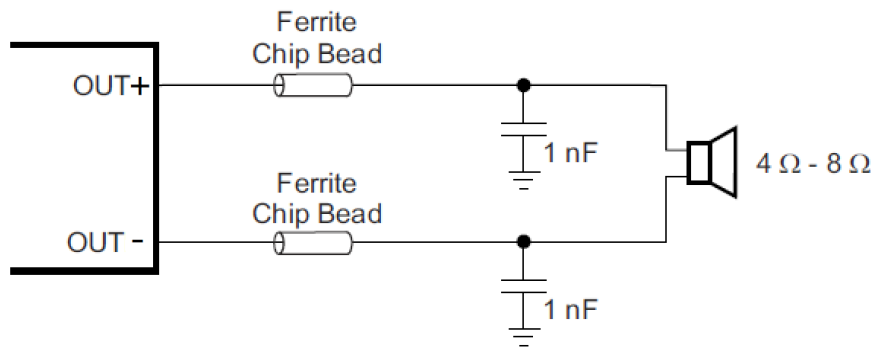


Figure 3 Output Filters with Ferrite Beads

There may be a few circuit instances where it is necessary to add a complete LC reconstruction filter. These circumstances might occur if there are nearby circuits which are sensitive to noise. In these cases, a classic second order Butterworth filter similar to those shown in the figures below can be used.

可能在一些应用场合需要添加一个完整的 LC 滤波器，比如附近有对噪声敏感的电，或 EMI 难以达到标准。此时，可以使用类似于下图所示的经典二阶巴特沃斯滤波器。

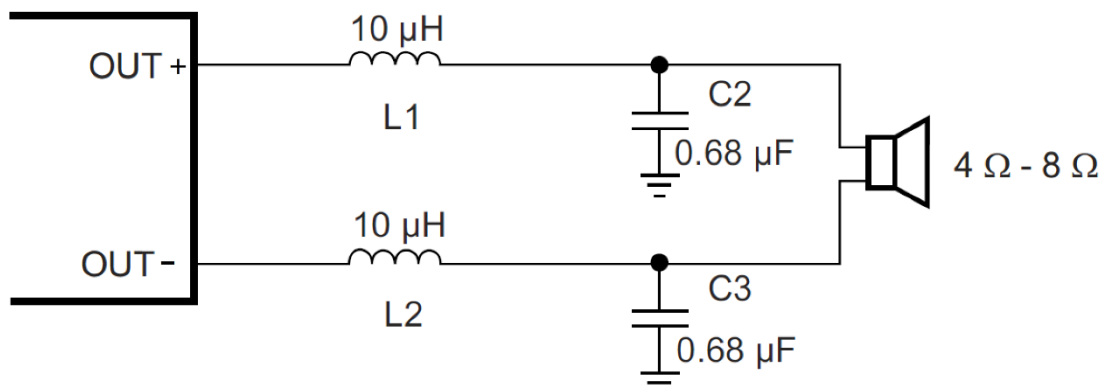


Figure 4 Output Filters with LC

### 2.3 PBTL Mode Configuration

The HT316C can be configured to drive a single speaker with the two output channels connected in parallel. This mode of operation is called Parallel Bridge Tied Load (PBTL) mode. This mode of operation effectively reduces the output impedance of the amplifier in half, which in turn reduces the power dissipated in the device due to conduction losses through the output FETs. Additionally, since the output channels are working in parallel, it also doubles the amount of current the speaker amplifier can source before hitting the over-current error threshold.

To place the HT316C into PBTL Mode, the LINP and LINN pins should be directly connected to Ground. When operated in PBTL mode, the output pins should be connected as shown in the Typical Application Circuit Diagrams.

In PBTL mode, the amplifier accepts its source signal from the R channel of the stereo signal.

HT316C 可工作在单声道输出的 PBTL 模式, 此时两个输出通道需要并联。在这种模式下, 输出线损降低了一般, 从而减小了功率损耗, 同时, 喇叭可流过的最大电流也翻倍了。

LINP 和 LINN 直接短接至地, 可使 HT316C 进入 PBTL 模式, 输出需要短接, 参见下图。此时, 信号从 R 通道进入。

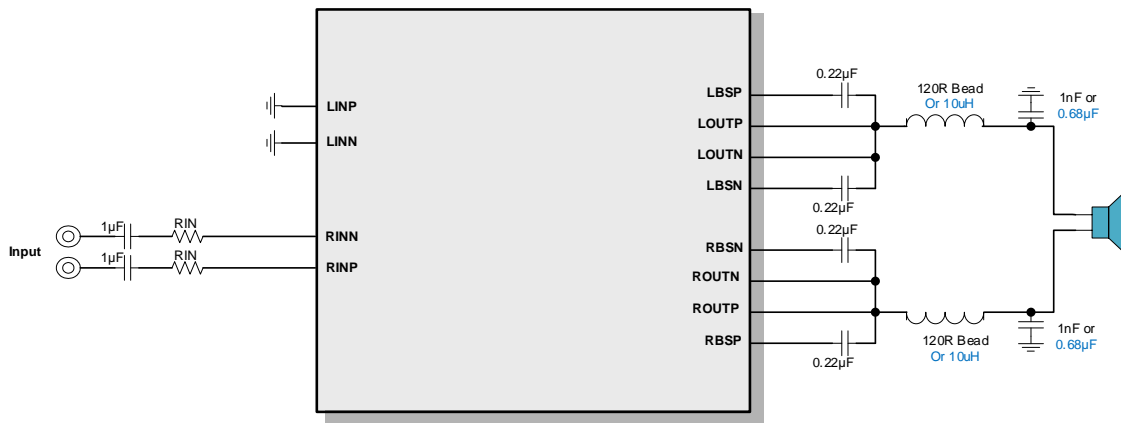


Figure 5 PBTL configuration

### 3 Startup, Shutdown

The HT316C employs a shutdown mode of operation designed to reduce supply current ( $I_{DD}$ ) to the absolute minimum level during periods of nonuse for power conservation. The  $\backslash$ SD input terminal should be held high during normal operation when the amplifier is in use. Pulling  $\backslash$ SD low will put the outputs to mute and the amplifier to enter a low-current state. It is not recommended to leave  $\backslash$ SD unconnected and pull  $\backslash$ SD down less than 100us, because amplifier operation would be unpredictable.

For a better power on and power-off pop performance, place the amplifier in the shutdown mode prior to delivering or removing the power supply.

HT316C 具有关断功能, 以使芯片进入低功耗状态。当  $\backslash$ SD 拉高时, 芯片进入工作状态; 当  $\backslash$ SD 拉低时, 芯片进入关断状态。

$\backslash$ SD 不建议悬空, 也不建议  $\backslash$ SD 低电平的状态小于 100us, 否则可能状态不定。

上下电时, 为减小 pop 声, 在上、下电前, 将功放关闭进入关断状态。

#### 4 Anti-Clipping Function (ACF mode)

HT316C can work in ACF mode by setting the \SD terminal, shown as follow.

HT316C 可工作在 ACF 模式, 通过设置 \SD 进入。

Table 1 \SD Terminal Configuration

VCTRL	Working Mode
<0.5V	Shutdown
1.8V~2.1V	ACF mode
2.5~5.5V	Normal mode

In ACF modes, HT316C attenuates system gain to an appropriate value when an excessive input is applied, so as not to cause the clipping at the differential signal output. In this way, the output audio signal is controlled in order to obtain a maximum output level without distortion. And HT316C also follows to the clips of the output waveform due to the decrease in the power-supply voltage.

在 ACF 模式下, 当电路检测到输入信号幅度过大而产生输出削顶时, HT316C 通过自动调整系统增益, 控制输出达到一种最大限度的无削顶失真功率水平, 由此大大改善了音质效果。此外, 当电源电压下降时, HT316C 也能自动衰减输出增益, 实现与 PVDD 下降值相匹配的最大限度无削顶输出水平。

The Attack time of ACF Function is a time interval until system gain falls to target attenuation gain -3dB when a big enough signal input. And, the Release Time is a time from target attenuation gain to not working of ACF. The maximum attenuation gain is 16dB.

ACF 模式下的启动时间 (Attack time) 指在突然输入足够大信号而产生输出削顶的条件下, ACF 启动对放大器的增益调整速率, 以 ms/dB 为单位; 释放时间 (Release time) 指产生削顶的输入条件消失, 增益退出衰减状态的速率, 以 ms/dB 为单位。HT316C 的最大衰减增益为 16dB。

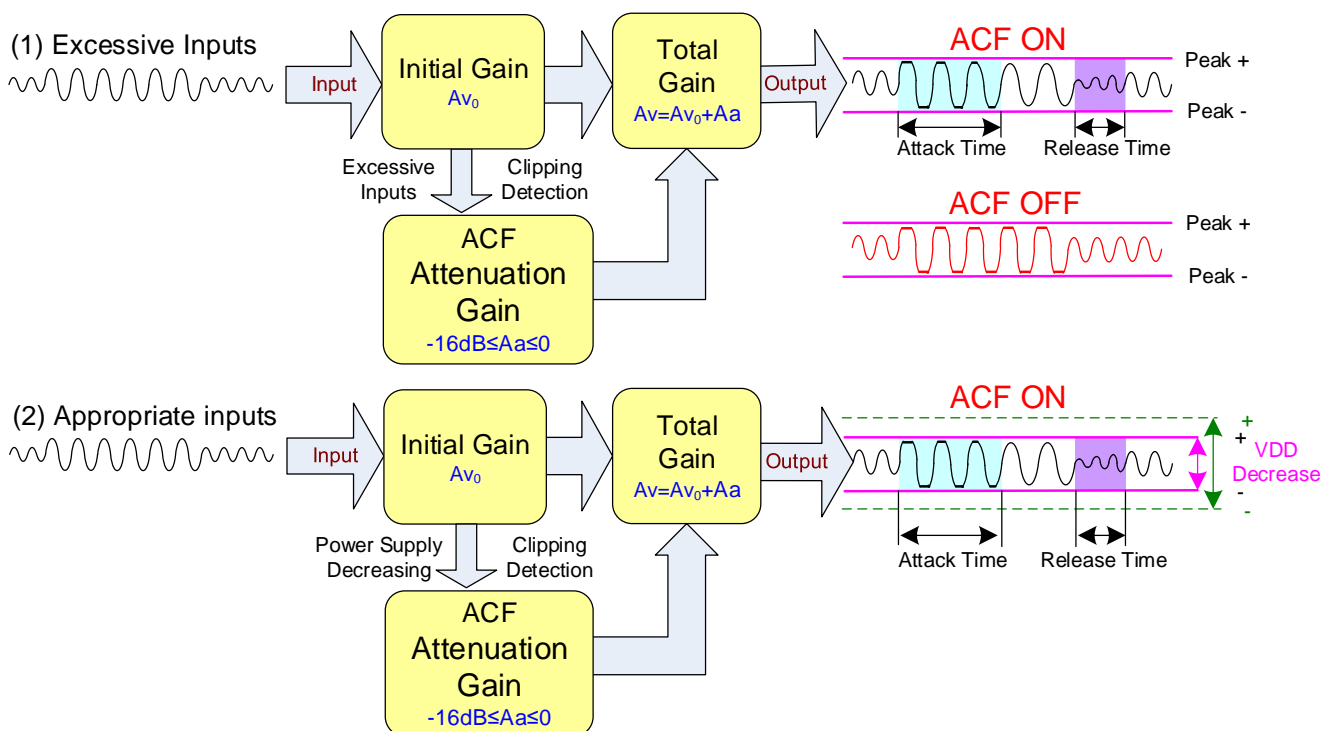


Figure 6 the ACF Function Operation Outline

Table 2 Attack time and Release time

ACF mode	Attack time	Release time
	50ms	64ms

In shutdown mode, HT316C shuts all circuit down and minimizes the power consumption. And, the output terminals become Weak Low (A high resistance grounded state).

## 5 GVDD Supply

The GVDD Supply is used to power the gates of the output full bridge transistors. Decouple GVDD with a X5R ceramic 1  $\mu$ F capacitor to GND. The GVDD supply is not intended to be used for external supply.

## 6 BSP and BSN Capacitors

The full H-bridge output stages use only NMOS transistors. Therefore, they require bootstrap capacitors for the high side of each output to turn on correctly. A 0.22 $\mu$ F ceramic capacitor of quality X5R or better, rated for at least 16 V, must be connected from each output to its corresponding bootstrap input. The bootstrap capacitors connected between the BSx pins and corresponding output function as a floating power supply for the high-side N-channel power MOSFET gate drive circuitry. During each high-side switching cycle, the bootstrap capacitors hold the gate-to-source voltage high enough to keep the high-side MOSFETs turned on.

## 7 Protection Function

HT316C has the protection functions such as Over-Current Protection function, Thermal Protection function, DC Detect Protection, Under-Voltage Protection and over voltage protection.

### (1) Over-current Protection function (OCP)

When a short circuit occurs between one output terminal and Ground, PVDD, or the other output, the over-current protection mode starts up. In the over current protection mode, the differential output terminal becomes a high impedance state. Once the short circuit conditions are eliminated, the over current protection mode can be cancelled automatically.

### (2) Thermal Protection function (OTP)

When excessive high temperature of HT316C (150 $^{\circ}$ C) is detected, the thermal protection mode starts up. In the thermal protection mode, the differential output terminal becomes Weak Low state (a state grounded through high impedance).

在关断模式（低功耗待机）下，芯片关闭所有功能并将功耗降低到最小，输出端为弱低电平状态（内部通过电阻接地）。

GVDD 电源用于为输出全桥晶体管的栅极供电。使用 X5R 陶瓷 1  $\mu$ F 电容器将 GVDD 与 GND 连接。GVDD 电源不用于外部电源。

全 H 桥输出级仅使用 NMOS 晶体管。因此，它们需要引导电容器，以使每个输出的高端正确开启。必须从每个输出端将额定电压至少为 16 V、质量为 X5R 或更高的 0.22 $\mu$ F 陶瓷电容器连接到相应的自举输入端。连接在 BSx 引脚和相应输出之间的自举电容器，用作高端 NMOS 栅极驱动电路的电源。在每个高端开关周期中，自举电容器保持栅极至源极电压足够高，以保持高端 MOSFET 导通。

HT316C 具有以下几种保护功能：输出端过流保护、片内过温保护、直流监测保护、欠压保护、过压保护。

### (1) 过流保护

当检测到一输出端对电源、对地、或对另一输出端短路时，过流保护启动，输出端切换至高阻态，防止芯片烧毁损坏。短路情况消除后，通过关断、唤醒一次芯片，或重新上电均能使芯片退出保护模式。

### (2) 过温保护

当检测到芯片内温度超过 150 $^{\circ}$ C 时，过温保护启动，正负输出端切换至弱低电平状态（内部通过高阻接地），防止芯片被热击穿损坏。

### (3) DC Detect Protection (DCP)

The HT316C has circuitry which will protect the speakers from DC current which might occur due to an internal amplifier error. The DC Detect fault will cause the amplifier to shutdown by changing the state of the outputs to Hi-Z.

A DCE event occurs when the output differential duty-cycle of either channel exceeds 60% for more than 420 msec at the same polarity. This feature protects the speaker from large DC currents or AC currents less than 2 Hz.

When OCP, OTP or DCP is activated, the SD/FAULT pin will be pulled low, and the error signal will be cleared. Therefore, after a delay time (Typ 1.3s), HT316C will try restart.

### (4) Over-voltage Protection function (OVP)

The HT316C device monitors the voltage on AVDD voltage. When the voltage on AVDD pin exceeds the over-voltage threshold (20V typ), the OVP circuit puts the device into shutdown mode. The device recovers automatically once the over-voltage condition has been removed.

### (5) Under-Voltage Protection (UVP)

This is the function to establish the under-voltage protection mode when power supply becomes lower than the detection voltage  $V_{UVLL}$  (Typ 4.2V), and the protection mode is canceled when the power supply becomes higher than the threshold voltage  $V_{UVLH}$  (Typ 4.4V). In the under-voltage protection mode, the differential output pin becomes weak low state (a stage grounded through resistivity). HT316C will start up within start-up time when the under-voltage protection mode is cancelled.

### (3) 直流监测保护

HT316C 具有保护扬声器免受由于内部放大器错误而产生的直流电流影响的电路。直流检测故障时,输出状态更改为 Hi-Z,致放大器关闭。

当任一通道在相同极性下的输出差占空比超过 60%超过 420 毫秒时,就会发生 DCE 事件。此功能可保护扬声器免受大直流电流或小于 2 Hz 的交流电流的影响。

当 OCP、OTP 或 DCP 发生时, \SD/FAULT 引脚拉低, 错误信号清除。因此, 经过一段延迟时间(Typ 1.3s)后, HT316C 将尝试重启。

### (4) 过压保护

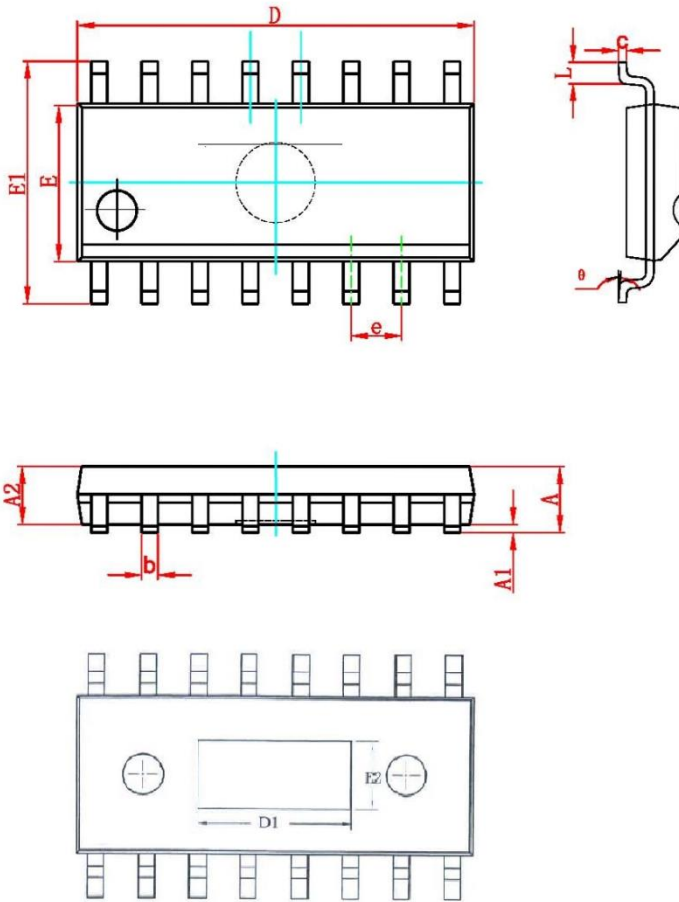
HT316C 监控 AVDD 电压上的电压。当 AVDD 引脚上的电压超过过电压阈值(20V 典型值)时, OVP 电路将 HT316C 置于关机模式。一旦消除过电压情况, 设备将自动恢复。

### (5) 欠压保护

该功能是在当电源低于检测电压  $V_{UVLL}$ (Typ 4.2V)时建立欠压保护模式, 当电源高于阈值电压  $V_{UVLH}$ (Typ 4.4V)时取消保护模式。在欠压保护模式下, 输出引脚变为弱下拉状态(通过电阻接地)。取消欠压保护模式后, HT316C 会在启动时间内启动。

**PACKAGE OUTLINE**

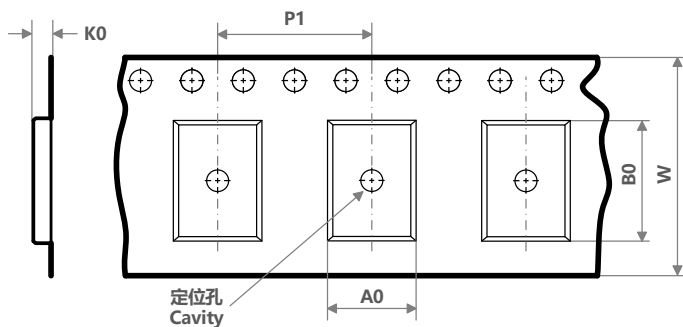
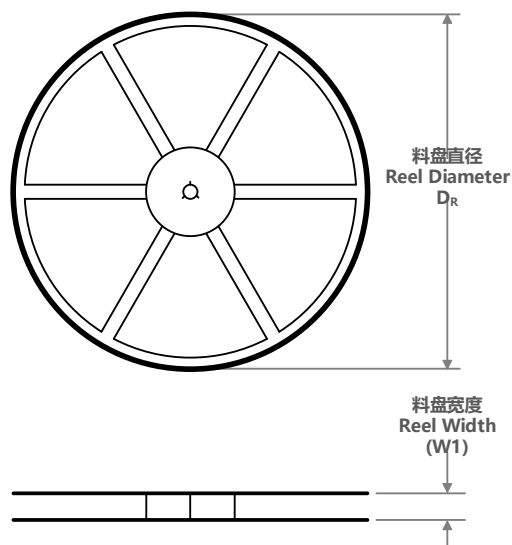
SPE (ESOP16)



Symbol	Size (mm)	
	MIN	MAX
A	-	1.75
A1	0.05	0.15
A2	1.30	1.50
b	0.39	0.48
c	0.21	0.26
D	9.70	10.10
D1	4.57(REF)	
E	3.70	4.10
E1	5.80	6.20
E2	2.41(REF)	
e	1.27(BSC)	
L	0.50	0.80
θ	0°	8°

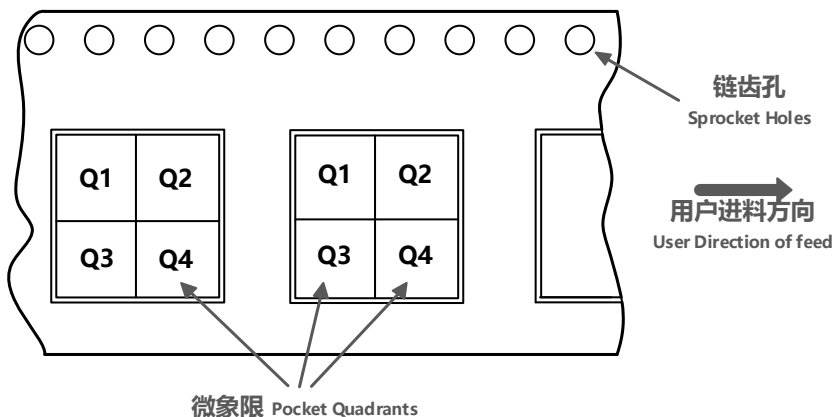


TAPE AND REEL INFORMATION

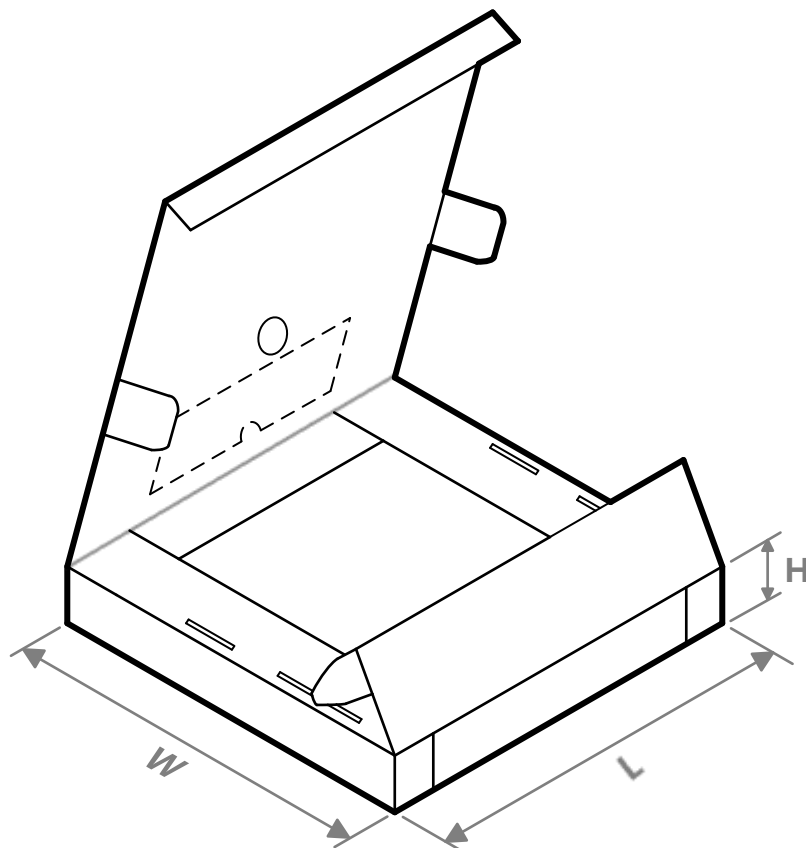


<b>A0</b>	Dimension designed to accommodate the component width; 料槽宽度
<b>B0</b>	Dimension designed to accommodate the component length; 料槽长度
<b>K0</b>	Dimension designed to accommodate the component thickness; 料槽厚度
<b>W</b>	Overall width of the carrier tape; 载带整体宽度
<b>P1</b>	Pitch between successive cavity centers; 相邻槽中心间距

编带 PIN1 方位象限分配  
Quadrant Assignments for Pin1 Orientation in Tape



器件料号 Part No.	封装类型 Package Type	封装标识 Package Abbr.	引脚数 Pins	SPQ	料盘直径 $D_R$ (mm)	料盘宽度 $W1$ (mm)	$A0$ (mm)	$B0$ (mm)	$K0$ (mm)	$P1$ (mm)	$W$ (mm)	Pin1 象限 Quadrant
HT316CSPER	ESOP	SPE	16	2500	330	12	6.5	10.3	2	8	16	Q1

**TAPE AND REEL BOX INFORMATION**


器件料号 Part No.	封装类型 Package Type	封装标识 Package Abbr.	引脚数 Pins	SPQ	长度 Length (mm)	宽度 Width (mm)	高度 Height (mm)
HT316CSPE	ESOP	SPE	16	5000	380	340	60

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